Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	("20050224781").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/03 16:39
S2	1	S1 and waveguide and carrier adj confinement	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 16:43
S12	35	Kneissl.in. and cladding and algan and ingan and (multiple-quantum adj well multiple adj quantum adj well mqw) and (nm nanometer angstrom)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:52
S13	30	S12 and @pd<"20041231"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 15:53
S18	90	Kneissl-M$.in.	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/02 16:18
S22	46	(Treat-D$ or Kneissl-M$).in. and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/02 16:22
S23	24	(Treat-D$ or Kneissl-M$).in. and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active and (undoped "not doped" intentionally adj doped)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/02 18:25
S24	24	Si-doped with undoped with barrier with active	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/02/02 19:20
S25	1	("5620907").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/02 18:25
S26	2	undoped near3 spacer with active with (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 15:52

S27	2	"826304".ap.	US-PGPUB; EPO; DERWENT; IBM_TDB	OR	ON	2006/02/03 15:52
S28	1	("20050224781").PN.	DERWENT	OR	OFF	2006/02/03 16:42
S29	4	(("6121634") or ("6563850") or ("20030132440") or ("6377597")).PN.	US-PGPUB; USPAT	OR	OFF	2006/02/03 18:35
S31	3	S29 and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:13
S32	1	S29 not S31	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 16:53
S33	10	(US-20020001864-$ or US-20040051107-$ or US-20050224781-$ or US-20030231679-$).did. or (US-6121634-$ or US-6597017-$ or US-6563850-$ or US-6303405-$ or US-6136623-$ or US-6252261-$).did.	US-PGPUB; USPAT	OR	OFF	2006/02/03 17:48
S34	6	S33 and concentration	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:12
S35	3	(("6,072,819") or ("6,118,801") or ("6,389,051")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/03 18:12
S36	3	S35 and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:15
S37	1	S35 and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active and transition	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:16
S38	3	S35 and (GaN InGaN InGaAlN GaAlN AlGaN InAlGaN GaAlInN) same active and undoped	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:16

S39	1996	(257/79,101,104).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/03 18:28
S40	2920	(257/79,103).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/03 18:28
S41	1139	257/14	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:30
S42	2884	S39 or S41	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:30
S43	4212	S39 S40 S41	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/03 18:30
S44	0	(("6121634") or ("6563850") or ("20030132440") or ("6377597")).PN.	EPO	OR	OFF	2006/02/03 18:35
S45	4	(("6121634") or ("6563850") or ("20030132440") or ("6377597")).PN.	DERWENT	OR	OFF	2006/02/03 18:35
S46	2	EP-908988-$.did.	EPO; DERWENT	OR	OFF	2006/02/03 18:36
S47	6	(US-4679199-$ ep-847117-$ ep-661782-$ ep-802442-$ wo-9713303-$ jp-04350988-$).did.	DERWENT; IBM_TDB	OR	OFF	2006/02/04 09:39
S49	6	(US-4679199-$ US-6185237-$ US-5636236-$ ep-802442-$ US-6373874-$ jp-04350988-$).did.	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:42
S50	4	S49 and (intrinsic undoped not adj doped)	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:49
S51	0	S49 and (intrinsic undoped not adj doped) near3 spacer	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:42
S52	73	barrier near3 "6" and laser adj diode	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:50
S53	32	S52 and (intrinsic undoped not adj doped)	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:50
S54	25	barrier near3 "6" with active and laser adj diode	USPAT; EPO; JPO	OR	OFF	2006/02/04 11:18
S55	17	S54 and (intrinsic undoped not adj doped)	USPAT; EPO; JPO	OR	OFF	2006/02/04 10:05

S56	100	barrier with (nm nanometer angstrom) with active and laser adj diode and concentration	USPAT; EPO; JPO	OR	OFF	2006/02/04 09:57
S57	61	S56 and (intrinsic undoped not adj doped)	USPAT; EPO; JPO	OR	OFF	2006/02/04 10:15
S58	52	S57 and (multiple mqw)	USPAT; EPO; JPO	OR	OFF	2006/02/04 10:16
S59	4	"6383829"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/04 11:06
S60	62	barrier with thickness with active same undoped and laser adj diode	USPAT; EPO; JPO	OR	OFF	2006/02/04 11:19
S61	122	barrier with thickness with active same undoped and laser adj diode	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2006/02/04 11:19
S62	77	S61 not (S54 or "52")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2006/02/04 11:19
S63	4	(US-20020001864-$).did. or (US-6121634-$ or US-6597017-$).did. or (EP-908988-$).did.	US-PGPUB; USPAT; DERWENT	OR	OFF	2006/02/04 11:29
S64	4	S63 and barrier	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/02/04 11:29